

Silicon Carbide Power MOSFET

C3M[™] MOSFET Technology

N-Channel Enhancement Mode

Features

- 3rd generation SiC MOSFET technology
- Optimized package with separate driver source pin
- High blocking voltage with low on-resistance
- High-speed switching with low capacitances
- Fast intrinsic diode with low reverse recovery (Q_{rr})
- Halogen free, RoHS compliant

Benefits

- Reduce switching losses and minimize gate ringing
- Higher system efficiency
- Reduce cooling requirements
- Increase power density
- Increase system switching frequency

Applications

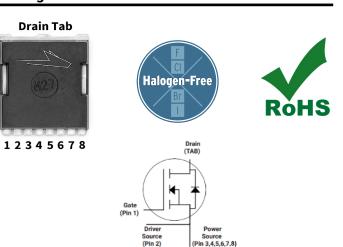
- Datacenter Power Supplies
- Telecom Power Supplies
- Energy Storage Systems
- Solar (PV) inverters
- High Voltage DC/DC converters

Maximum Ratings ($T_c = 25$ °C unless otherwise specified)

Symbol	Parameter	Value	Unit	Note	
V _{DSmax}	Drain - Source Voltage		650	V	
V _{GSmax}	Gate - Source Voltage		-8/+19	V	Note: 1
		T _C = 25°C	49		Fig. 19 Note: 2
Ι _D	Continuous Drain Current, V _{GS} = 15 V	T _C = 100°C	33	A	
I _{D(pulse)}	Pulsed Drain Current, Pulse width t_P limited by T_{jmax}	132	А	Fig. 22	
P _D	Power Dissipation, T _c =25°C, T _J = 175 °C	164	W	Fig. 20 Note: 2	
Tj	Junction Temperature	-40 to +175	°C		
$T_{C}^{}$, $T_{stg}^{}$	Case Temperature and Storage Temperature	-40 to +150	°C		
TL	Solder Temperature, 1.6mm (0.063") from case for 10s	260	°C		

Note (1): Recommended turn off / turn on gate voltage V_{GS} - 4V...0V / +15V Note (2): Verified by design

Package



Part Number	Package	Marking
C3M0045065L	TOLL	C3M0045065L

Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Conditions	Note
$V_{(\text{BR})\text{DSS}}$	Drain-Source Breakdown Voltage	650			V	V_{GS} = 0 V, I _D = 100 µA	
V _{GS(th)} Gate Thr		1.8	2.6	3.6	V	$V_{DS} = V_{GS}$, $I_D = 4.84$ mA $V_{DS} = V_{GS}$, $I_D = 4.84$ mA, $T_J = 175^{\circ}$ C	Fig. 11
	Gate Threshold Voltage		2.2		V		
I _{DSS}	Zero Gate Voltage Drain Current		1	50	μA	V_{DS} = 650 V, V_{GS} = 0 V	
I _{GSS}	Gate-Source Leakage Current		10	250	nA	V_{GS} = 15 V, V_{DS} = 0 V	
D	Drain-Source On-State Resistance		45	60	mΩ	V _{GS} = 15 V, I _D = 17.6 A	Fig. 4, 5, 6
$R_{DS(on)}$			61			V_{GS} = 15 V, I_{D} = 17.6 A, T_{J} = 175°C	
a	Transconductance		12		s	V _{DS} = 20 V, I _{DS} = 17.6 A	Fig. 7
g _{fs}	Transconductance		11			V _{DS} = 20 V, I _{DS} = 17.6 A, T _J = 175°C	
C_{iss}	Input Capacitance		1621			V _{GS} = 0 V, V _{DS} = 400 V	
C_{oss}	Output Capacitance	ĺ	101		pF	V _{GS} = 0 V, V _{DS} = 400 V F = 1 Mhz	Fig. 17, 18
C _{rss}	Reverse Transfer Capacitance		8		1	$V_{AC} = 25 \text{ mV}$	
E _{oss}	Coss Stored Energy		20		μJ	V _{DS} = 600 V, F = 1 Mhz	
$C_{\text{o}(\text{er})}$	Effective Output Capacitance (Energy Related)		126		pF		Note: 3
C _{o(tr)}	Effective Output Capacitance (Time Related)	İ	178	1	pF	$V_{GS} = 0 V, V_{DS} = 0 400V$	
E _{on}	Turn-On Switching Energy (Body Diode FWD)		53			V_{DS} = 400 V, V_{GS} = -4 V/15 V, I_{D} = 17.6A,	Fig. 23
EOFF	Turn-Off Switching Energy (Body Diode FWD)		10		μJ	$R_{G(ext)} = 2.5 \Omega$, L= 99 μH, T _J = 25°C FWD = Internal Body Diode	
t _{d(on)}	Turn-On Delay Time		7	1			
tr	Rise Time		9			$V_{DD} = 400 \text{ V}, V_{GS} = -4 \text{ V}/15 \text{ V}$ $I_D = 17.6 \text{ A}, R_{G(ext)} = 2.5 \Omega,$ $Timing relative to V_{DS}$	Fig. 26
$t_{d(off)}$	Turn-Off Delay Time		17		ns		
t _f	Fall Time		6		1	Inductive load	
R _{G(int)}	Internal Gate Resistance		3	1	Ω	f = 1 MHz, V _{AC} = 25 mV	
Q_{gs}	Gate to Source Charge		20			V _{DS} = 400 V, V _{GS} = -4 V/15 V	
Q_{gd}	Gate to Drain Charge		16	1	nC	I _D = 17.6 A	Fig. 12
Qg	Total Gate Charge		59	1		Per IEC60747-8-4 pg 21	

Electrical Characteristics (T_c = 25°C unless otherwise specified)

Note (3): C_{o(er)}, a lumped capacitance that gives same stored energy as Coss while Vds is rising from 0 to 400V C_{o(tr)}, a lumped capacitance that gives same charging time as Coss while Vds is rising from 0 to 400V



Reverse Diode Characteristics (T $_{\rm c}$ = 25 $^{\circ}{\rm C}$ unless otherwise specified)

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V	Diode Forward Voltage	4.8		V	$V_{_{\rm GS}}$ = -4 V, I $_{_{\rm SD}}$ = 8.8 A, T $_{_{\rm J}}$ = 25 °C	Fig. 8, 9, 10
V _{SD}		4.2		V	V _{GS} = -4 V, I _{SD} = 8.8 A, T _J = 175 °C	
ls	Continuous Diode Forward Current		28	А	V _{GS} = -4 V, T _C = 25°C	
I _{S, pulse}	Diode pulse Current		132	А	$V_{_{GS}}$ = -4 V, pulse width $t_{_{P}}$ limited by $T_{_{jmax}}$	
t _{rr}	Reverse Recover time	10		ns		
Q _{rr}	Reverse Recovery Charge	207		nC	V _{GS} = -4 V, I _{SD} = 17.6 A, V _R = 400 V dif/dt = 6580 A/µs, T _J = 25 °C	
I _{rrm}	Peak Reverse Recovery Current	38		А		
t _{rr}	Reverse Recover time	12		ns		
Q _{rr}	Reverse Recovery Charge	94		nC	V _{GS} = -4 V, I _{SD} = 17.6 A, V _R = 400 V dif/dt = 2260 A/μs, Τ ₁ = 25 °C	
l _{rrm}	Peak Reverse Recovery Current	14		А		

Thermal Characteristics

Symbol	Parameter	Тур.	Unit	Test Conditions	Note
$R_{\theta JC}$	Thermal Resistance from Junction to Case	0.64	°C/W		Fig. 21



Typical Performance

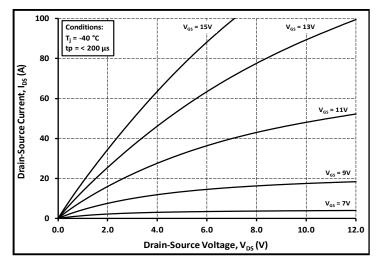
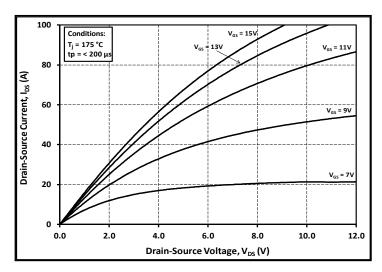
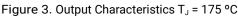
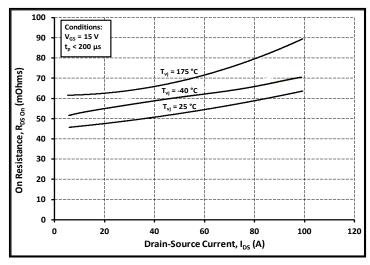
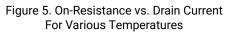


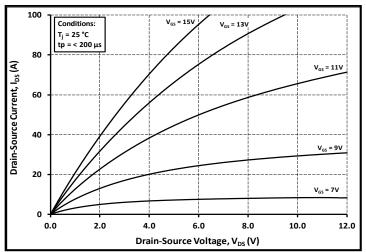
Figure 1. Output Characteristics T_J = -40 °C



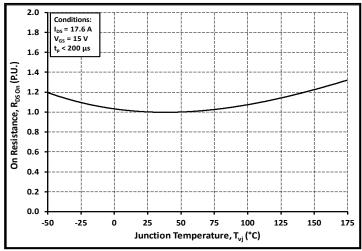














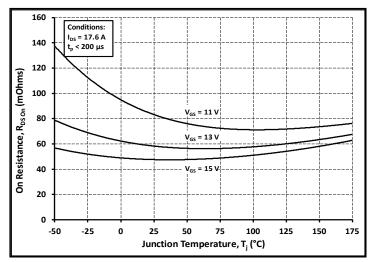


Figure 6. On-Resistance vs. Temperature For Various Gate Voltage

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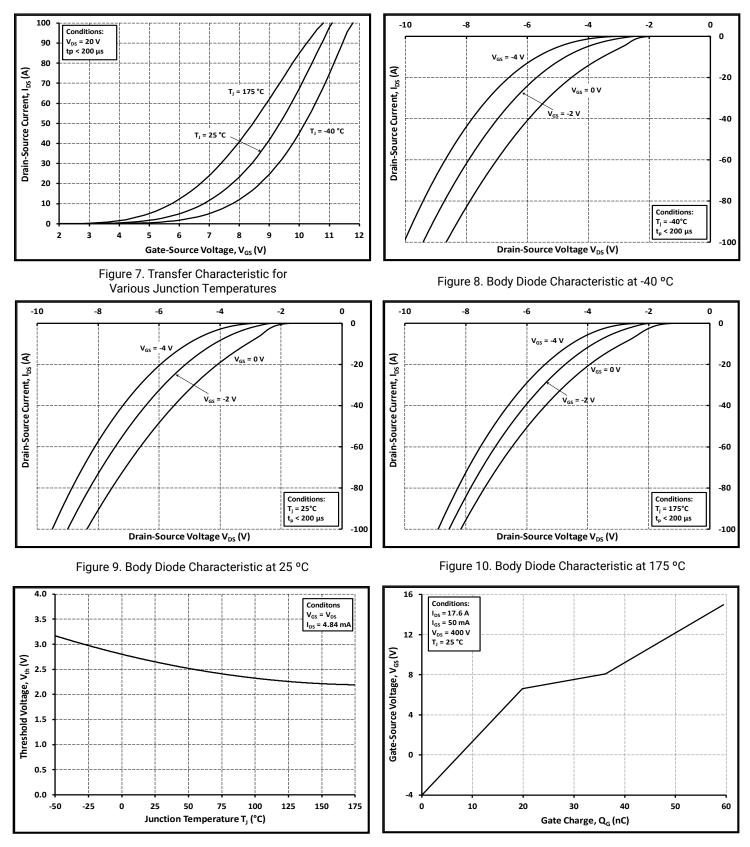
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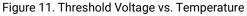
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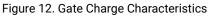
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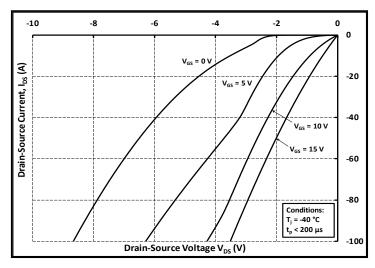


Figure 13. 3rd Quadrant Characteristic at -40 °C

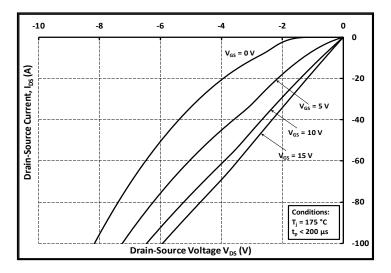
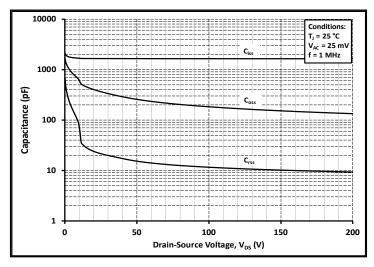
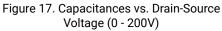


Figure 15. 3rd Quadrant Characteristic at 175 °C





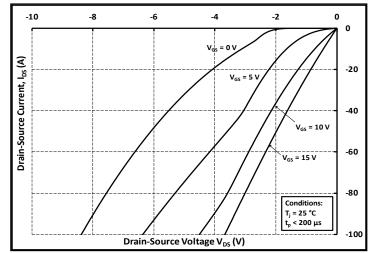


Figure 14. 3rd Quadrant Characteristic at 25 °C

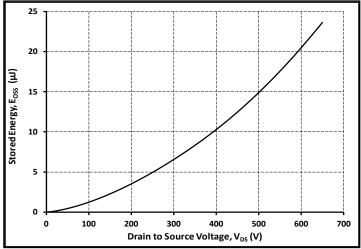


Figure 16. Output Capacitor Stored Energy

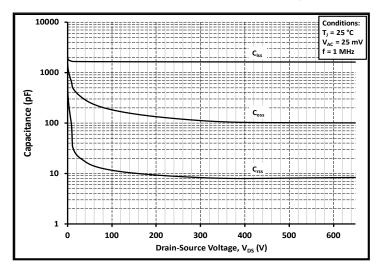
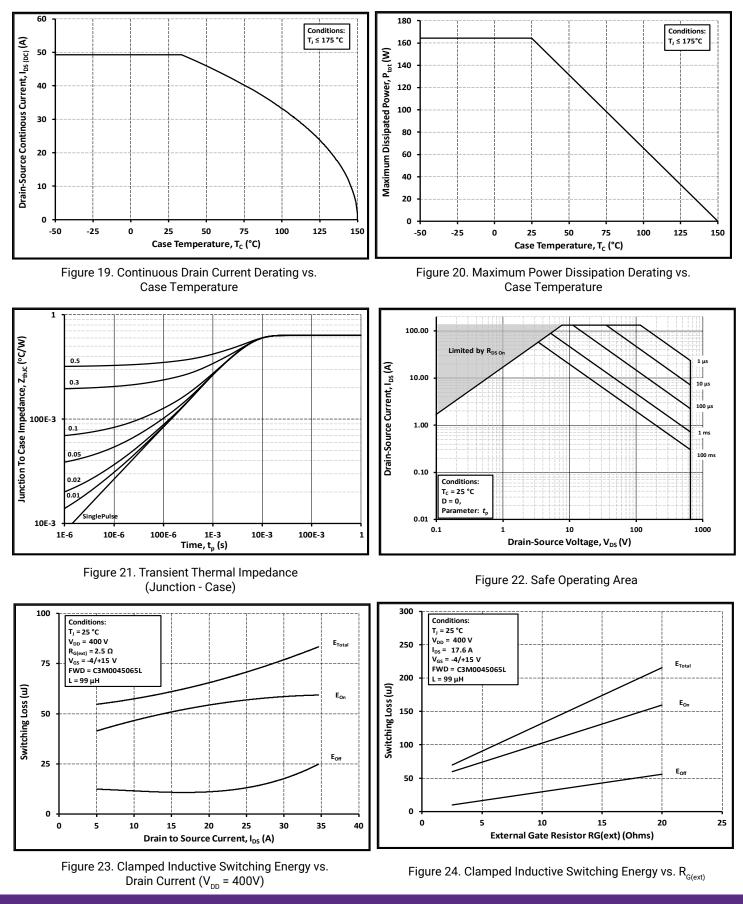


Figure 18. Capacitances vs. Drain-Source Voltage (0 - 650V)

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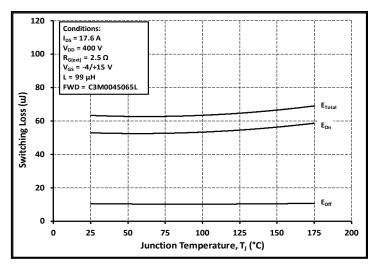


Figure 25. Clamped Inductive Switching Energy vs. Temperature

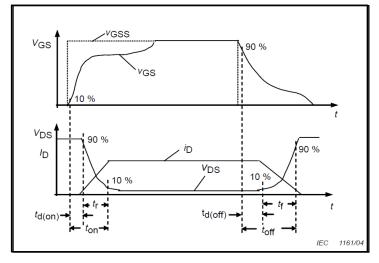


Figure 27. Switching Times Definition

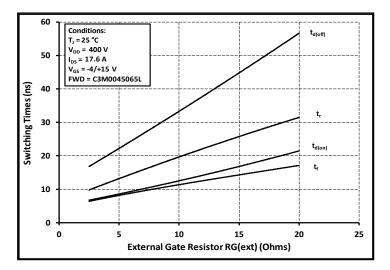


Figure 26. Switching Times vs. R_{G(ext)}

Test Circuit Schematic



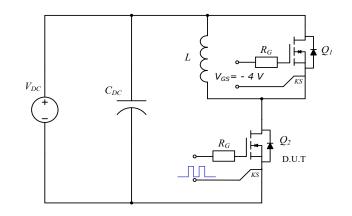
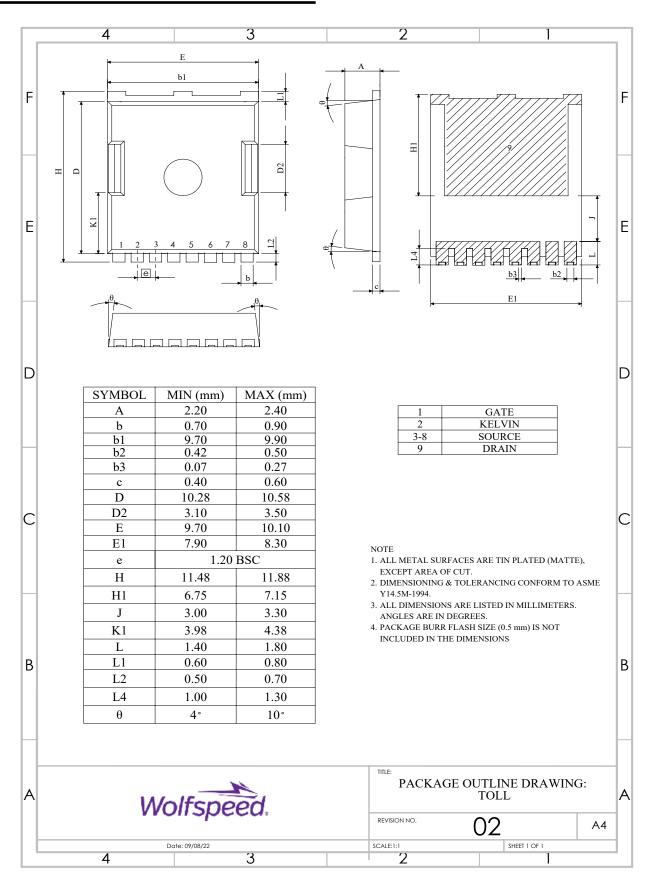


Figure 28. Clamped Inductive Switching Waveform Test Circuit

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Package Dimensions

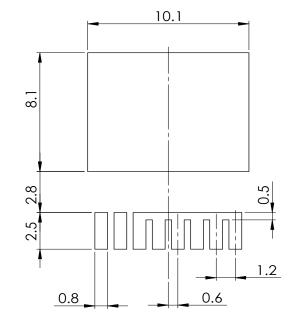




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Recommended Solder Pad Layout

(Note: All Dimensions are listed in Millimeters)



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Revision history

Document Version	Date of release	Descriptiion of changes
1.0	September-2022	Initial datasheet

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